



Attorney Docket No. SAM-0274

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Min-su Kim, *et al.*

Serial No.: 09/994,146

Filing Date: November 26, 2001

Title: SEMICONDUCTOR DEVICE HAVING SILICON-ON-INSULATOR
STRUCTURE AND METHOD OF FABRICATING THE SAME

Examiner: Hu, S.

Group Art Unit: 2811

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3-3-03

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Vanessa Marakas

Vanessa Marakas

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Assistant Commissioner for Patents

Washington, DC 20231

AMENDMENT AFTER FINAL REJECTION

Sir:

The following is in response to the Office Action dated December 3, 2002. Please amend the application as follows.

In the claims:

Please add the following new claims:

- Sub 027
C1
18. (New) A semiconductor device having a silicon-on-insulator (SOI) structure, comprising:
an insulating layer;
an insular silicon region having first conductivity-type impurity ions formed on

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01 FC:1201 84.00 CH
02 FC:1202 288.00 CH